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Data Sheet

September 2013

N-Channel Power MOSFET 60V, 70A, 14 mΩ

These are N-Channel power MOSFETs manufactured using the MegaFET process. This process, which uses feature sizes approaching those of LSI circuits, gives optimum utilization of silicon, resulting in outstanding performance. They were designed for use in applications such as switching regulators, switching converters, motor drivers and relay drivers. These transistors can be operated directly from integrated circuits.

Formerly developmental type TA78440.

Ordering Information

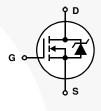
PART NUMBER	PACKAGE	BRAND
RFP70N06	TO-220AB	RFP70N06

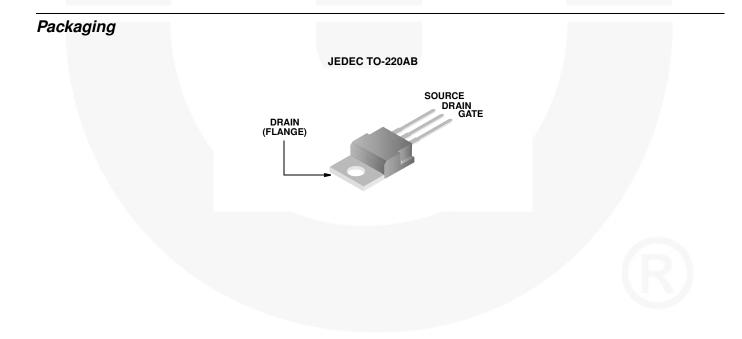
NOTE: When ordering use the entire part number. Add the suffix 9A to obtain the TO-263AB variant in tape and reel, e.g. RF1S70N06SM9A.

Features

- 70A, 60V
- $r_{DS(on)} = 0.014\Omega$
- Temperature Compensated PSPICE[®] Model
- Peak Current vs Pulse Width Curve
- UIS Rating Curve (Single Pulse)
- 175⁰C Operating Temperature
- Related Literature
 - TB334 "Guidelines for Soldering Surface Mount Components to PC Boards"

Symbol





Absolute Maximum Ratings $T_C = 25^{\circ}C$, Unless Otherwise Specified

	RFP70N06	UNITS
Drain to Source Voltage (Note 1)VDSS	60	V
Drain to Gate Voltage (R _{GS} = 20kΩ) (Note 1)V _{DGR}	60	V
Continuous Drain CurrentID	70	А
Pulsed Drain Current (Note 3)	Refer to Peak Current Curve	
Gate to Source Voltage V _{GS}	<u>±20</u>	V
Single Pulse Avalanche Rating EAS	Refer to UIS Curve	А
Power Dissipation PD	150	W
Linear Derating Factor	1.0	W/ ^o C
Operating and Storage Temperature	-55 to 175	°C
Maximum Temperature for Soldering		
Leads at 0.063in (1.6mm) from Case for 10s.	300	°C
Package Body for 10s, See Techbrief 334	260	oC

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. $T_J = 25^{\circ}C$ to $150^{\circ}C$.

Electrical Operations $T_C = 25$ 0, onless otherwise operation	Electrical Specifications	$T_{C} = 25^{\circ}C$, Unless Otherwise Specified
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PARAMETER	SYMBOL	TEST CONDITION	S MIN	TYP	MAX	UNITS
Drain to Source Breakdown Voltage	BV _{DSS}	$I_D = 250\mu A$, $V_{GS} = 0V$ (Figure 11) 60	-	-	V
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}$, $I_D = 250\mu A$ (Figure 1	0) 2	-	4	V
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = 60V, V_{GS} = 0V$	-	-	1	μA
		$V_{DS} = 0.8 \text{ x Rated BV}_{DSS}, T_{C} = 150^{\circ}C$		-	25	μA
Gate to Source Leakage Current	IGSS	V _{GS} = ±20V	-	-	±100	nA
Drain to Source On Resistance (Note 2)	rDS(ON)	$I_D = 70A, V_{GS} = 10V$ (Figure 9)	-	-	0.014	Ω
Turn-On Time	t _(ON)	$ \begin{array}{l} V_{DD} = 30V, \ I_D \approx \ 70A, \ R_L = 0.43\Omega, \\ V_{GS} = 10V, \ R_{GS} = 2.5\Omega \\ (\mbox{Figure 13}) \end{array} $		-	190	ns
Turn-On Delay Time	^t d(ON)			10	-	ns
Rise Time	t _r			137	-	ns
Turn-Off Delay Time	^t d(OFF)			32	-	ns
Fall Time	t _f		-	24	-	ns
Turn-Off Time	t(OFF)		-	-	73	ns
Total Gate Charge	Q _{g(TOT)}	$V_{GS} = 0V \text{ to } 20V \qquad V_{DD} = 48V,$	I _D = 70A, -	120	156	nC
Gate Charge at 10V	Q _{g(10)}	$V_{GS} = 0V \text{ to } 10V$ $R_{L} = 0.68\Omega$ $I_{g(REF)} = 2.2$	2mA -	65	85	nC
Threshold Gate Charge	Q _{g(TH)}	$V_{GS} = 0V \text{ to } 2V$ (Figure 13)	-	5.0	6.5	nC
Input Capacitance	C _{ISS}	V _{DS} = 25V, V _{GS} = 0V, f = 1MHz (Figure 12)		2250	-	pF
Output Capacitance	C _{OSS}			792	-	pF
Reverse Transfer Capacitance	C _{RSS}			206	-	pF
Thermal Resistance, Junction to Case	$R_{\theta JC}$		-	-	1.0	°C/W
Thermal Resistance, Junction to Ambient	R_{\thetaJA}	TO-220	-	-	62	°C/W
		-	-	-		-

Source to Drain Diode Specifications

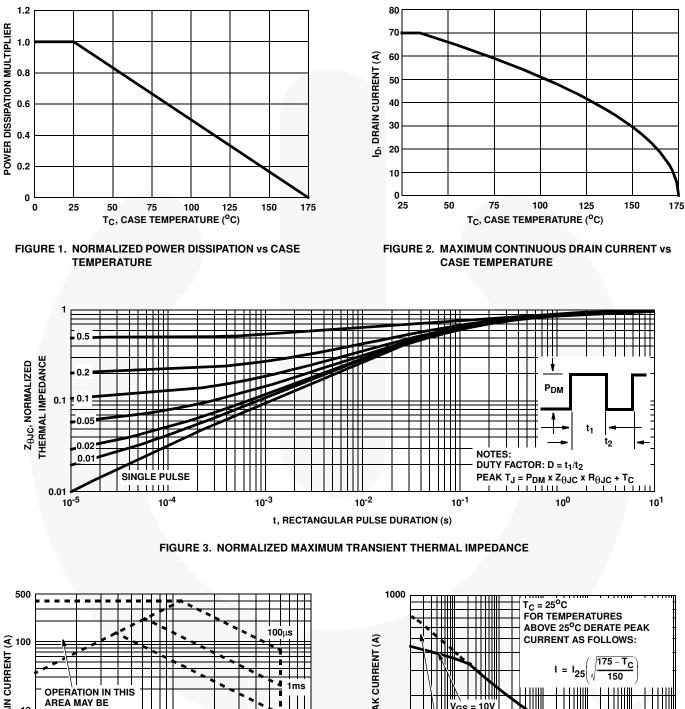
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	ТҮР	MAX	UNITS
Source to Drain Diode Voltage	V _{SD}	I _{SD} = 70A		-	1.5	V
Reverse Recovery Time	t _{rr}	I_{SD} = 70A, d I_{SD} /dt = 100A/µs		-	52	ns

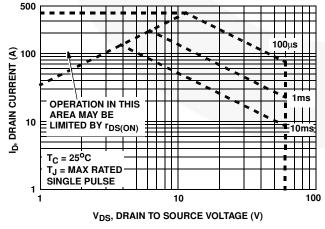
NOTES:

2. Pulse test: pulse width \leq 300ms, duty cycle \leq 2%.

3. Repetitive rating: pulse width is limited by maximum junction temperature. See Transient Thermal Impedance curve (Figure 3) and Peak Current Capability Curve (Figure 5).

Typical Performance Curves T_C = 25°C, Unless Otherwise Specified







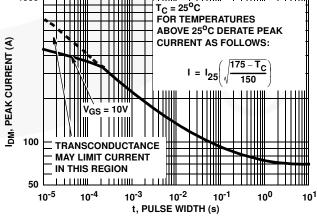
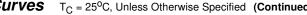
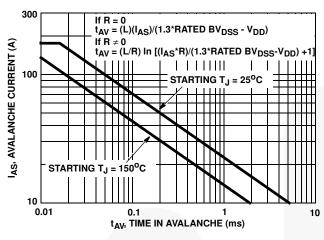


FIGURE 5. PEAK CURRENT CAPABILITY

Typical Performance Curves T_C = 25°C, Unless Otherwise Specified (Continued)







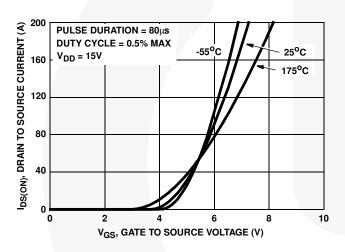
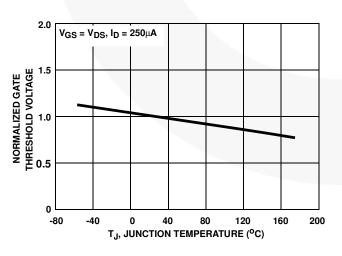
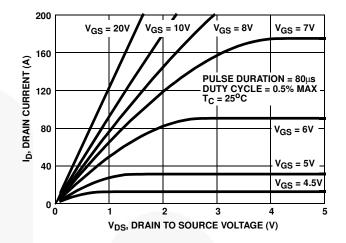


FIGURE 8. TRANSFER CHARACTERISTICS









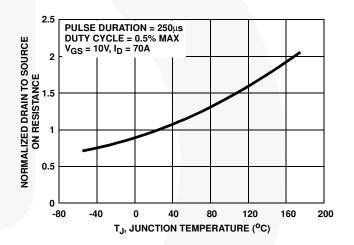


FIGURE 9. NORMALIZED DRAIN TO SOURCE ON **RESISTANCE vs JUNCTION TEMPERATURE**

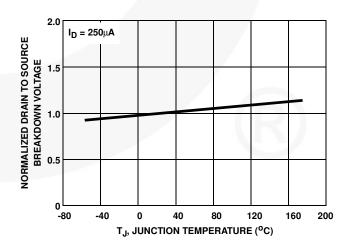


FIGURE 11. NORMALIZED DRAIN TO SOURCE BREAKDOWN **VOLTAGE vs JUNCTION TEMPERATURE**

Typical Performance Curves $T_{C} = 25^{\circ}C$, Unless Otherwise Specified (Continued)

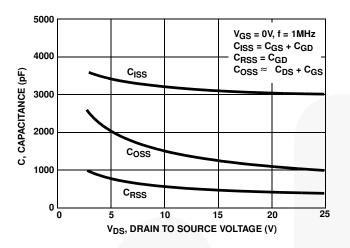


FIGURE 12. CAPACITANCE vs DRAIN TO SOURCE VOLTAGE

R_G

FIGURE 14. UNCLAMPED ENERGY TEST CIRCUIT

V_{DS}

L

DUT

0.01Ω

las

VDD

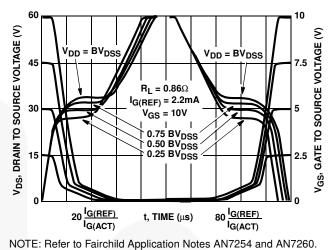


FIGURE 13. NORMALIZED SWITCHING WAVEFORMS FOR CONSTANT GATE CURRENT

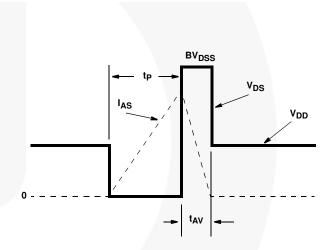


FIGURE 15. UNCLAMPED ENERGY WAVEFORMS

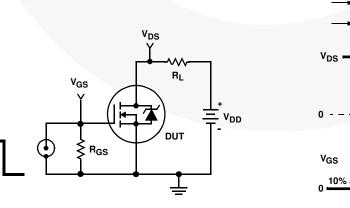


FIGURE 16. SWITCHING TIME TEST CIRCUIT

 $\begin{array}{c|c} & t_{ON} & & & \\ & t_{d(ON)} & & \\ & t_{d(OFF)} & \\ & t_{r} & \\ & & \\ DS & 90\% & \\ \end{array}$

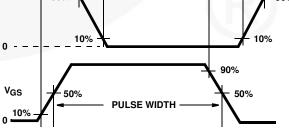


FIGURE 17. SWITCHING WAVEFORMS

Test Circuits and Waveforms

VARY tp TO OBTAIN

REQUIRED PEAK IAS

VGS

tр

٥v

V_{GS}

Test Circuits and Waveforms (Continued)

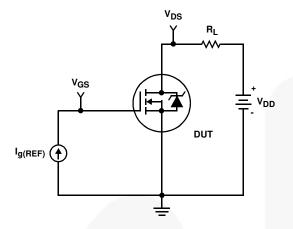
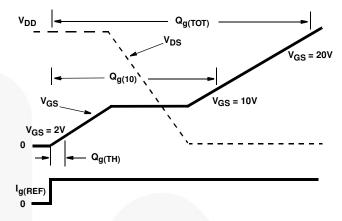


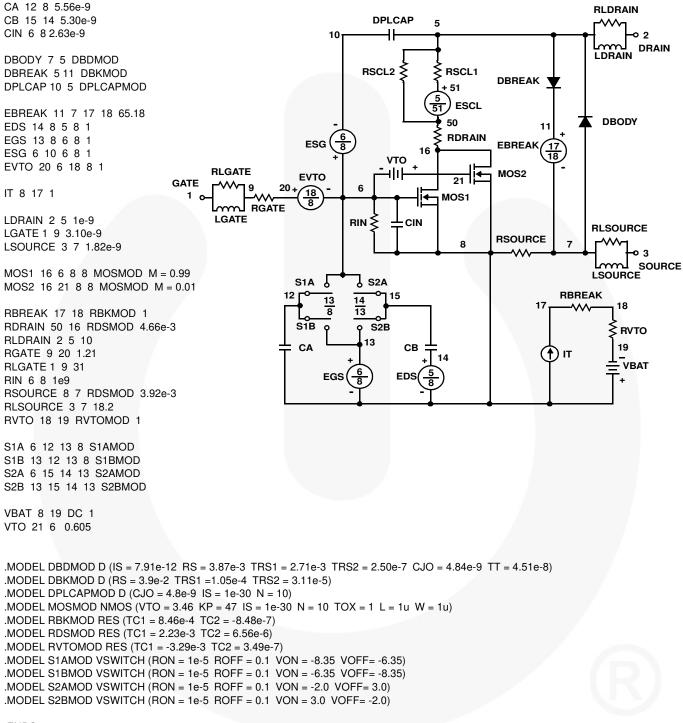
FIGURE 18. GATE CHARGE TEST CIRCUIT





PSPICE Electrical Model

.SUBCKT RFG70N06 2 1 3 ; rev 3/20/92



.ENDS

NOTE: For further discussion of the PSPICE model, consult **A New PSPICE Sub-circuit for the Power MOSFET Featuring Global Temperature Options**; written by William J. Hepp and C. Frank Wheatley.



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